TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT process)

2SC5232

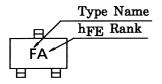
General Purpose Amplifier Applications Switching and Muting Switch Application

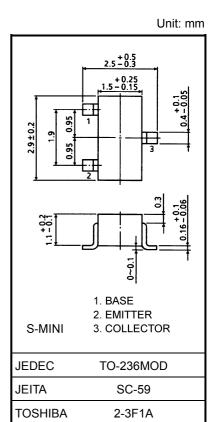
• Large collector current: IC = 500 mA (max)

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	15	V
Collector-emitter voltage	V _{CEO}	12	V
Emitter-base voltage	V _{EBO}	5	V
Collector current	Ic	500	mA
Base current	ΙΒ	50	mA
Collector power dissipation	PC	150	mW
Junction temperature	Tj	125	°C
Storage temperature range	T _{stg}	-55~125	°C

Marking





Weight: 0.012 g (typ.)

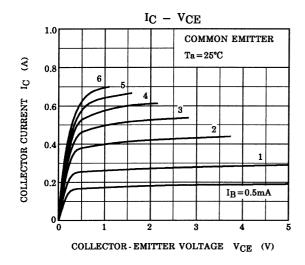


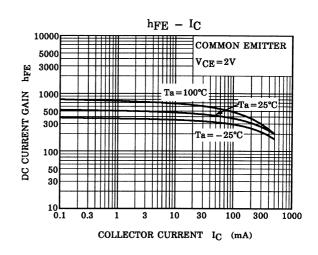
Electrical Characteristics (Ta = 25°C)

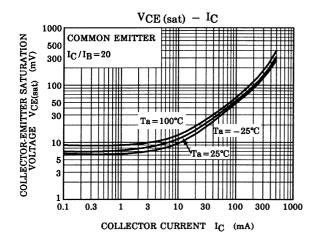
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I _{CBO}	V _{CB} = 15 V, I _E = 0	_	_	0.1	μА
Emitter cut-off current		I _{EBO}	V _{EB} = 5 V, I _C = 0	_	_	0.1	μА
DC current gain		h _{FE} (Note)	V _{CE} = 2 V, I _C = 10 mA	300	_	1000	
Collector-emitter saturation voltage		V _{CE} (sat) (1)	$I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$	_	15	30	mV
		V _{CE} (sat) (2)	$I_C = 200 \text{ mA}, I_B = 10 \text{ mA}$	_	110	250	
Base-emitter saturation voltage		V _{BE (sat)}	$I_C = 200 \text{ mA}, I_B = 10 \text{ mA}$	_	0.87	1.2	V
Transition frequency		f _T	V _{CE} = 2 V, I _C = 10 mA	80	130	_	MHz
Collector output capacitance		C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz	_	4.2		pF
Collector-emitter on resistance		R _{on}	$I_B = 1 \text{ mA}, V_{in} = 1 V_{rms}, f = 1 \text{ kHz}$	_	0.9	_	Ω
Switching time	Turn-on time	t _{on}	OUTPUT 10μs VBB= VCC -3V = 6V	_	85	_	
	Storage time	t _{stg}		_	170	_	ns
	Fall time	t _f	Duty cycle ≤ 2% I _{B1} = -I _{B2} = 5 mA	_	40	_	

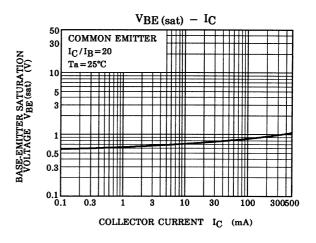
Note: hFE classification A: 300~600, B: 500~1000

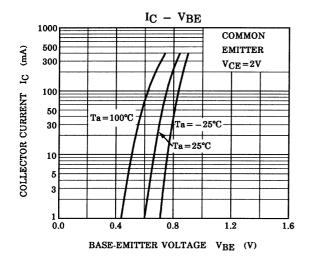
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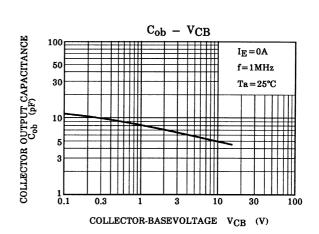


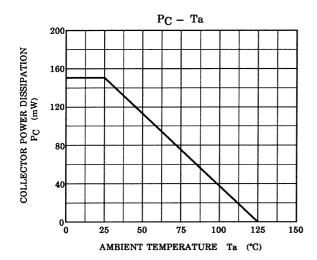












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